

## High IIP3 PIN Diode Variable Attenuator 1.7 - 2.0 GHz

Rev. V4

### Features

- RoHs and ELV compliant
- 1.4 dB Insertion Loss, Typical
- 1.4:1 VSWR, Typical
- 21 dB Attenuation, Typical
- 45 dBm IIP3, Typical  
(1 MHz Offset, @ + 0 dBm Pinc)
- 0 – 1.66 Volts Control Voltage @ 1.50 mA Typical

### Extra Features

- Covers the following Bands:
  - DCS
  - PCS
  - UMTS/WCDMA/CDMA
  - TD-S\_CDMA
  - SCDMA
- Usable Bandwidth: 1.50 GHz to 2.50 GHz
- 1.8 dB Insertion Loss, Typical
- 2:1 VSWR, Typical
- 18.5 dB Attenuation, Typical

### Description and Applications

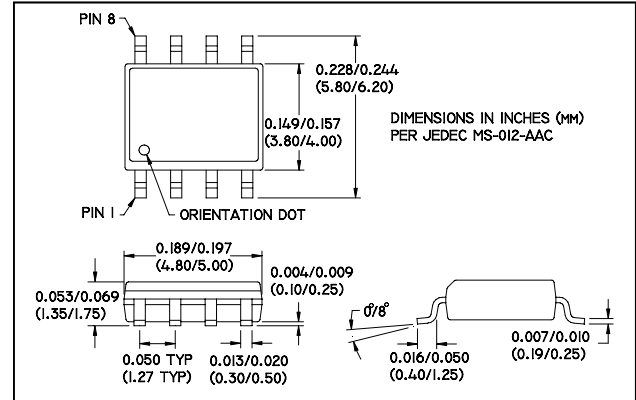
M/A-COM's MA4VAT2004-1061T is a HMIC PIN Diode Variable Attenuator which utilizes an integrated 90 degree 3dB hybrid with a pair of Silicon PIN Diodes to perform the required attenuation function as D.C. Voltage (Current) is applied.

This device operates from 0 to 1.66 Volts at 1.50mA typical control current for maximum attenuation. The user can add external biasing resistors to the bias ports for higher voltage requirements as required.

M/A-COM's MA4VAT2004-1061T PIN Diode Variable Attenuator is designed for AGC Circuit Applications requiring:

- Lower Insertion Loss
- Lower distortion through attenuation
- Large dynamic range for wide spread spectrum applications

### PIN Configuration (Topview)



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PIN	Function	Comments
1	DC1	
2	GND	
3	GND	
4	RFin/out	Symmetrical as RF Input/Output
5	RFout/in	Symmetrical as RF Input/Output
6	GND	
7	GND	
8	DC2	

### Absolute Maximum Ratings<sup>1,2</sup> @ T = +25 °C

Parameter	Maximum Ratings
Operating Temperature	-40 °C to +85 °C
Storage Temperature	-65 °C to +150 °C
Junction Temperature	+175 °C
RF C.W. Incident Power	+33 dBm C.W.
Reversed Current @ -30 V	-50nA
Control Current	50mA per Diode

1. All the above are at Room Temperature except as noted
2. Exceeding the above Limits may cause permanent damage

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### Electrical Specifications @ +25 °C

Parameter	Frequency Band	Unit	Min	Typ	Max
<b>No DC Bias Low Loss State</b>					
Insertion Loss	1.70 GHz – 2.00 GHz	dB	-	1.4	1.8
Input Return Loss		dB	13	15	-
Output Return Loss		dB	13	15	-
P1dB		dBm	30	-	-
IIP3		dBm	47	49	-
Control Voltage		V	-	0V @ 0uA	-
<b>DC Bias RF Attenuation State</b>					
Maximum Attenuation	1.70 GHz – 2.00 GHz	dB	20	24	-
Input Return Loss @ Max Attenuation		dB	18	21	-
Output Return Loss @ Max Attenuation		dB	18	21	-
IP3		dBm	36	39	-
Control Voltage @ Max Attenuation		V	-	1.66V @ 1.50mA	-
Current@Max Attenuation	Bias =1.66V	mA	1.2		2.4

### Typical RF Performance Over Industry Designated RF Frequency Bands <sup>3,4</sup>

Band		Freq	I. Loss	Att.	R. Loss	IIP3	Phase -Relative-
		(MHz)	(dB)	(dB)	(dB)	(dBm)	(Degree)
DCS	RX	1710-1785	1.6	22	13	50	+15°
	TX	1805-1880	1.6	22	13	50	
PCS	RX	1850-1910	1.6	21	13	50	+10°
	TX	1930-1990	1.6	21	13	50	
UMTS	RX	1920-1980	1.6	20	13	50	-5°
WCDMA/CDMA	TX	2110-2170	1.8	20	13	50	
TD-S-CDMA	-	2010-2025	1.7	20	13	50	-2°
SCDMA	-	1800-2200	1.8	20	13	50	-10°

3. All are typical values only.

4. Relative phase is the measured Insertion Phase Difference between Insertion Loss and the 20dB Attenuation State.  
(Please refer to the plots below)

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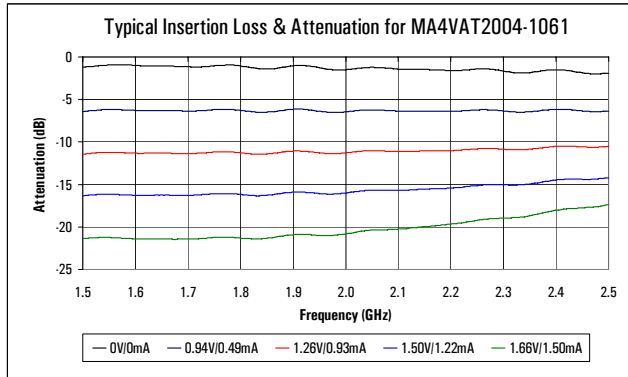


## High IIP3 PIN Diode Variable Attenuator 1.7 - 2.0 GHz

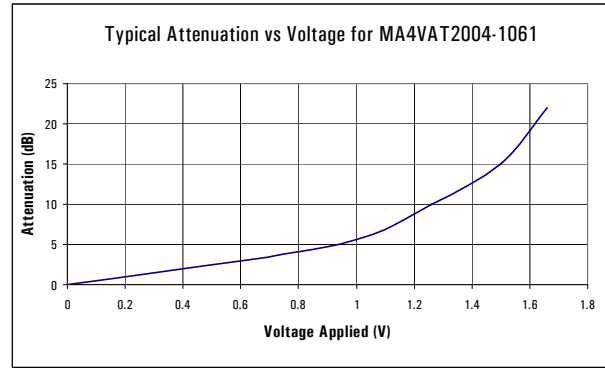
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### Plots of Typical RF Characteristics @ + 25 °C

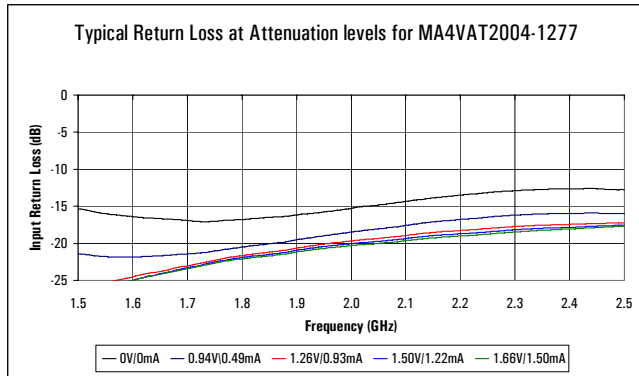
**Typical Insertion Loss & Attenuation Plot**



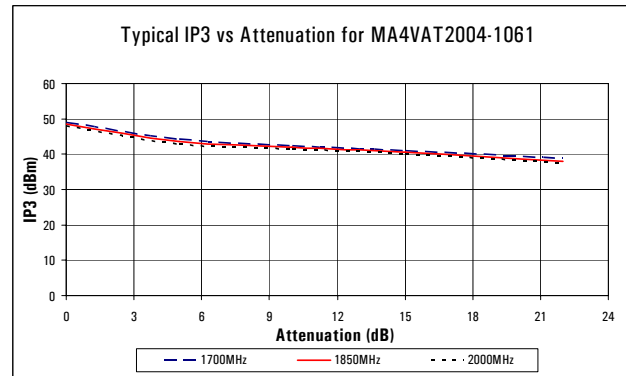
**Typical Attenuation Vs Voltage Plot**



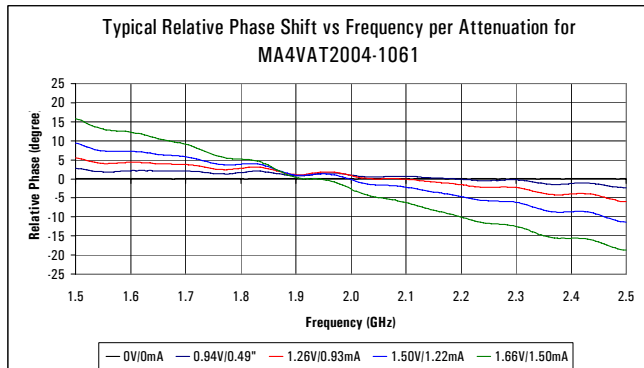
**Typical Return Loss @ All Attenuation Levels Plot**



**Typical IIP3 Vs Attenuation Plot**



**Typical Relative Phase Shift Per Attenuation (Voltage) Plot**



For Reference ONLY:

- Low Loss = 0.00V, @0.00mA
- 5 dB Attenuation = 0.94V, @0.49mA
- 10 dB Attenuation = 1.26V, @0.93mA
- 15 dB Attenuation = 1.50V, @1.22mA
- 20 dB Attenuation = 1.66V, @1.50mA

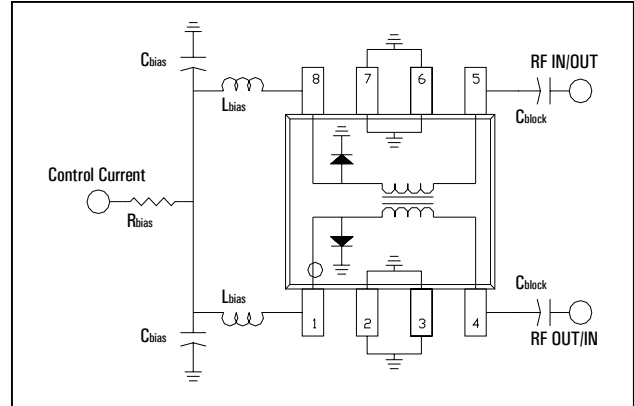
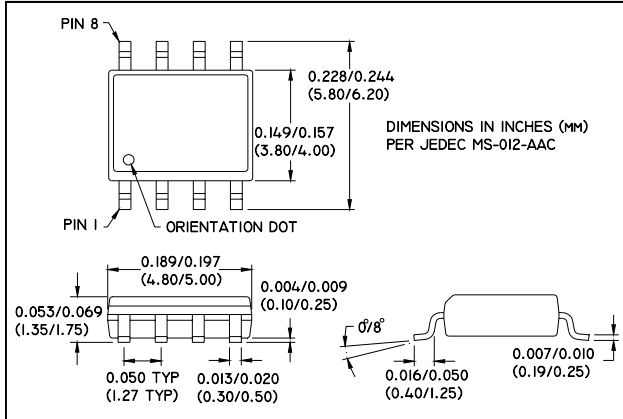
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### Package Pin Designation, External Components, and Equivalent Circuit



### Ordering Information

Part Number	Package
MA4VAT2004-1061T	Tape and Reel

### External Bias Components

Rbias= 680 Ohms ( 1.66 V, 1.50 mA )  
Lbias= 150 nH  
Cbias =100 pF  
Cblock =100 pF